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Old Company Name in Catalogs and Other Documents

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MAEC TECHNICAL NEWS

No. M16C-70-0104

Information of M16C/6N product type name change and
restriction on the electrical characteristic.

Classification

Corrections and supplementary
explanation of document
 Notes
 Knowhow
 Others

Concerned Products

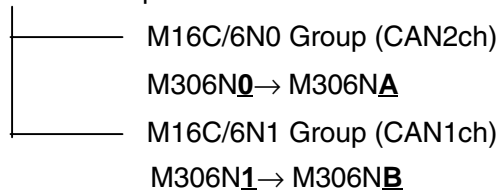
M16C/6N0 Group M306N0FGTFP
 M16C/6N1 Group M306N1FGTFP

1. Change of M16C/6N product type name

The Flash MCU of M16C/6N group has been improved about power consumption and radiation noise characteristics.

Thereby, M16C/6N product type name changed as follows.

- M16C/6N Group



- M16C/6N Group product type name

OLD	NEW
M306N0FGTFP	M306NAFGTFP
M306N1FCTFP	M306NBFCTFP

2. Restriction on the electrical characteristic

The differences of electrical characteristic between M306N0FGTFP/M306NBFCTFP and M306NAFGTFP/M306NBFCTFP is the following.

- (1) Electrical characteristics (refer to 2/4)
- (2) A-D conversion characteristics (refer to 3/4)
- (3) D-A conversion characteristics (refer to 4/4)

[M16C/6N Group Data Sheet Rev.A1]

Table 21-3. Electrical characteristics(referenced to VCC=5V,VSS=0V,Ta=-40 to 85°C, f(XIN)=16MHZ unless otherwise specified)

Symbol	Parameter	Measuring condition	Standard			Unit
			Min.	Typ.	Max.	
V _{OH}	HIGH output voltage P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70, P72 to P77, P80 to P84, P86, P87, P90, P92 to P97, P100 to P107	I _{OH} =-5mA	0.6V _{CC}			V
V _{OH}	HIGH output voltage P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70, P72 to P77, P80 to P84, P86, P87, P90, P92 to P97, P100 to P107	I _{OH} =-200μA	0.9V _{CC}			V
V _{OH}	HIGH output voltage X _{OUT}	HIGHPOWER	I _{OH} =-1mA	3.0		V
		LOWPOWER	I _{OH} =-0.5mA	3.0		V
	HIGH output voltage X _{COU} T	HIGHPOWER	With no load applied		3.0	V
		LOWPOWER	With no load applied		1.6	V
V _{OL}	LOW output voltage P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P84, P86, P87, P90 to P97, P100 to P107	I _{OL} =5mA			0.4V _{CC}	V
V _{OL}	LOW output voltage P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P84, P86, P87, P90 to P97, P100 to P107	I _{OL} =200μA			0.1V _{CC}	V
V _{OL}	LOW output voltage X _{OUT}	HIGHPOWER	I _{OL} =1mA		2.0	V
		LOWPOWER	I _{OL} =0.5mA		2.0	V
	LOW output voltage X _{COU} T	HIGHPOWER	With no load applied		0	V
		LOWPOWER	With no load applied		0	V
V _{T+} -V _{T-}	Hysteresis HOLD, RDY, TA0IN to TA4IN, TB0IN to TB2IN, INT0 to INT5, ADTRG, CTS0, CTS1, CLK0, CLK1, TA2OUT to TA4OUT, NMI K10 to K13		0.2		0.8	V
V _{T+} -V _{T-}	Hysteresis RESET, CNVss, BYTE		0.2		1.8	V
I _{IH}	HIGH input current P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70, P72 to P77, P80 to P87, P90, P92 to P97, P100 to P107, XIN, RESET, CNVss, BYTE	V _I =5V			5.0	A
I _{IL}	LOW input current P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P107, XIN, RESET, CNVss, BYTE	V _I =0V			-5.0	A
R _{PULLUP}	Pull-up resistance P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70, P72 to P77, P80 to P84, P86, P87, P90, P92 to P97, P100 to P107	V _I =0V	30.0	50.0	167.0	k
R _{XIN}	Feedback resistance X _{IN}			1.0		M
R _{XCIN}	Feedback resistance X _{CIN}			6.0		M
V _{RAM}	RAM retention voltage	When clock is stopped	2.0			V
I _{CC}	Power supply current	In single-chip mode, the output pins are open and other pins are V _{SS}	f(X _{IN}) = 16MHz Square wave, no division	65.0		mA
			f(X _{CIN}) = 32kHz Square wave	200.0		A
			f(X _{CIN}) = 32kHz When WAIT instruction is executed	4.0		A
			T _a = 25°C When clock is stopped		1.0	A
		T _a = 85°C When clock is stopped		20.0	A	

[Restriction on the characteristic of M306N0FGTFFP]

Table 21-3. Electrical characteristics(referenced to VCC=5V,VSS=0V,Ta=-40 to 85°C, f(XIN)=16MHZ unless otherwise specified)

Symbol	Parameter	Measuring condition	Standard			Unit
			Min.	Typ.	Max.	
V _{OH}	HIGH output voltage P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70, P72 to P77, P80 to P84, P86, P87, P90, P92 to P97, P100 to P107	I _{OH} =-5mA	0.6V _{CC}			V
V _{OH}	HIGH output voltage P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70, P72 to P77, P80 to P84, P86, P87, P90, P92 to P97, P100 to P107	I _{OH} =-200μA	0.9V _{CC}			V
V _{OH}	HIGH output voltage X _{OUT}	HIGHPOWER	I _{OH} =-1mA	3.0		V
		LOWPOWER	I _{OH} =-0.5mA	3.0		V
	HIGH output voltage X _{COU} T	HIGHPOWER	With no load applied		3.0	V
		LOWPOWER	With no load applied		1.6	V
V _{OL}	LOW output voltage P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P84, P86, P87, P90 to P97, P100 to P107	I _{OL} =5mA			0.4V _{CC}	V
V _{OL}	LOW output voltage P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P84, P86, P87, P90 to P97, P100 to P107	I _{OL} =200μA			0.1V _{CC}	V
V _{OL}	LOW output voltage X _{OUT}	HIGHPOWER	I _{OL} =1mA		2.0	V
		LOWPOWER	I _{OL} =0.5mA		2.0	V
	LOW output voltage X _{COU} T	HIGHPOWER	With no load applied		0	V
		LOWPOWER	With no load applied		0	V
V _{T+} -V _{T-}	Hysteresis HOLD, RDY, TA0IN to TA4IN, TB0IN to TB2IN, INT0 to INT5, ADTRG, CTS0, CTS1, CLK0, CLK1, TA2OUT to TA4OUT, NMI K10 to K13		0.2		0.8	V
V _{T+} -V _{T-}	Hysteresis RESET, CNVss, BYTE		0.2		1.8	V
I _{IH}	HIGH input current P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70, P72 to P77, P80 to P87, P90, P92 to P97, P100 to P107, XIN, RESET, CNVss, BYTE	V _I =5V, When BCLK is 10MHz or less			5.0	A
I _{IL}	LOW input current P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P107, XIN, RESET, CNVss, BYTE	V _I =0V, When BCLK is 10MHz or less			-5.0	A
R _{PULLUP}	Pull-up resistance P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70, P72 to P77, P80 to P84, P86, P87, P90, P92 to P97, P100 to P107	V _I =0V	30.0	50.0	167.0	k
R _{XIN}	Feedback resistance X _{IN}			1.0		M
R _{XCIN}	Feedback resistance X _{CIN}			6.0		M
V _{RAM}	RAM retention voltage	When clock is stopped	2.0			V
I _{CC}	Power supply current	In single-chip mode, the output pins are open and other pins are V _{SS}	f(X _{IN}) = 16MHz Square wave, no division	65.0	105.0	mA
			f(X _{CIN}) = 32kHz Square wave	200.0		A
			f(X _{CIN}) = 32kHz When WAIT instruction is executed	4.0		A
			T _a = 25°C When clock is stopped		1.0	A
		T _a = 85°C When clock is stopped		20.0	A	

○ = Changed part

[M16C/6N Group Data Sheet Rev.A1]

Table 21-4. A-Dconversion characteristics (referenced to $V_{CC}=AV_{CC}=V_{REF}=5V$, $V_{SS}=AV_{SS}=0V$, $T_a=25^{\circ}C$, $f(X_{IN})=16MHz$ unless otherwise specified)

Symbol	Parameter	Measuring condition	Standard			Unit	
			Min.	Typ.	Max.		
-	Resolution	$V_{REF}=V_{CC}$			10	Bits	
		$V_{REF}=V_{CC}-5V$			± 3	LSB	
-	Absolute accuracy	Sample & hold function enabled (10bit) $V_{REF}=V_{CC}=5V$	AN0 to AN7 input			± 3	LSB
			A00 to A07 input			± 3	LSB
			AN20 to AN27 input			± 3	LSB
			ANEX0, ANEX1 input, External op-amp connection mode			± 7	LSB
		Sample & hold function enabled (8bit) $V_{REF}=V_{CC}=5V$			± 2	LSB	
RLADDER	Ladder resistance	$V_{REF}=V_{CC}$	10		40	k	
tCONV	Conversion time (10bit)		3.3			s	
tCONV	Conversion time (8bit)		2.8			s	
tsAMP	Sampling time		0.3			s	
VREF	Reference voltage		2		V_{CC}	V	
VIA	Analog input voltage		0		V_{REF}	V	

Note. Divide the frequency if $f(X_{IN})$ exceeds 10MHz, and make ϕ_{AD} equal to or lower than 10MHz.

[Restriction on the characteristic of M306N0FGTFP]

Table 21-4. A-Dconversion characteristics (referenced to $V_{CC}=AV_{CC}=V_{REF}=5V$, $V_{SS}=AV_{SS}=0V$, $T_a=40$ to $85^{\circ}C$, $f(X_{IN})=16MHz$, $f_{2AD}=8MHz$ unless otherwise specified)

Symbol	Parameter	Measuring condition (Note1)	Standard			Unit		
			Min.	Typ.	Max.			
-	Resolution	$V_{REF}=V$			10	Bits		
-	Absolute accuracy	Sample & hold function enabled (10bit)	$V_{REF}=V_{CC}=5V$	AN0 to AN7 input	0 to 0.5V		± 10	LSB
				AN00 to AN07 input	0.5 to 1.25V		± 8	
				AN20 to AN27 input	1.25 to 3.85V		± 4	
				ANEX0, 1 in put	3.85 to 4.5V		± 8	
				Analog input voltage	4.5 to 5V		No guarantee V _{REF}	
RLADDER	Ladder resistance	$V_{REF}=V_{CC}$	10		40	k		
tCONV	Conversion time (10bit)		3.3			s		
tsAMP	Sampling time		0.3			s		
VREF	Reference voltage		4.2		V_{CC}	V		
VIA	Analog input voltage		0		5	V		

Note 1. Assumed output impedance of 100 Ω at test.

 = Changed part

[M16C/6N Group Data Sheet Rev.A1]

Table 21-5. D-A conversion characteristics (referenced to $V_{CC}=5V, V_{SS}=AV_{SS}=0V, V_{REF}=5V, T_a=25^\circ C, f(X_{IN})=16MHz$ unless otherwise specified)

Symbol	Parameter	Measuring condition	Standard			Unit
			Min.	Typ.	Max.	
-	Resolution				8	Bits
-	Absolute accuracy				1.0	%
t_{su}	Setup time				3	s
R_o	Output resistance		4	10	20	k
I_{VREF}	Reference power supply input current	(Note 1)			1.5	mA

Note 1. This applies when using one D-A converter, with the D-A register for the unused D-A converter set to "00". The A-D converter's ladder resistance is not included. Also, when the V_{REF} is unconnected at the A-D control register, I_{VREF} is sent.

[Restriction on the characteristic of M306N0FGTFP]

Table 21-5. D-A conversion characteristics (referenced to $V_{CC}=5V, V_{SS}=AV_{SS}=0V, V_{REF}=5V, T_a=40$ to $85^\circ C, f(X_{IN})=16MHz, f_{2AD}=8MHz$ unless otherwise specified)

Symbol	Parameter	Measuring condition	Standard			Unit
			Min.	Typ.	Max.	
-	Resolution				8	Bits
-	Absolute accuracy (Note 1)				3.0	%
t_{su}	Setup time				3	s
R_o	Output resistance		4	10	20	k
I_{VREF}	Reference power supply input current	(Note 2)			1.5	mA

Note 1. Guarantee for absolute accuracy is up to maximum of $\pm 3.0\%$ ($\pm 150mV$) according to analog output voltage characteristic shown in the shown below. Analog output voltage characteristic Y is set to

$$Y = 0.96X + 0.13 [V]$$

However, X sets D-A input code value to $n(n-256)$ and is set to

$$X = 5[V] \cdot \frac{n}{256}$$

Maximum error on plus side: $Y = 0.96X + 0.28$,

Maximum error on minus side: $Y = 0.96X - 0.02$.

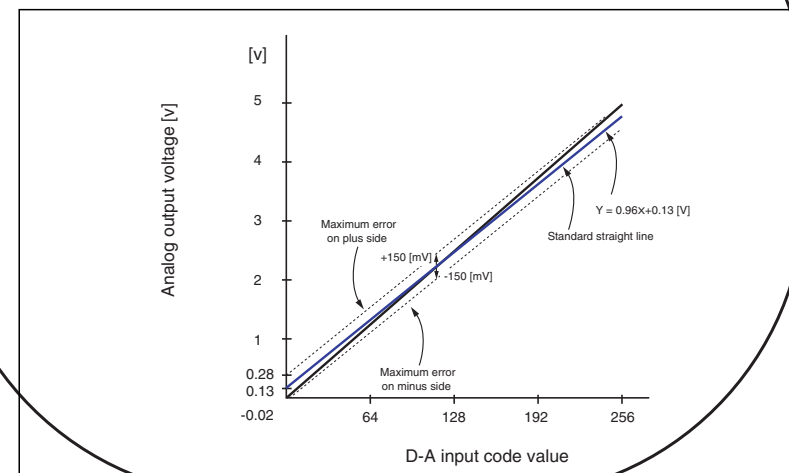


figure 1.21.01. Analog output voltage characteristic of the D-A converter

Note 2. In case one D-A converter is used and the value of the D-Register of the unused D-A converter is "FF16". Resistance of ladder register of the A-D converter is not included I_{VREF} flows even when the A-D control register is configured as not connected to V_{REF} .

 = Changed part